## NSN 5961-01-059-6782

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Inclosure Material:
Plastic
Semiconductor Material:
Gallium arsenide
Voltage Rating In Volts Per Characteristic:
3.0 reverse voltage, instantaneous
Current Rating Per Characteristic:
1.00 amperes forward current, average preset and 50.00 milliamperes source cutoff current preset
Power Rating Per Characteristic:
120.0 milliwatts small-signal input power, common-collector preset
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0